

Fig. 1

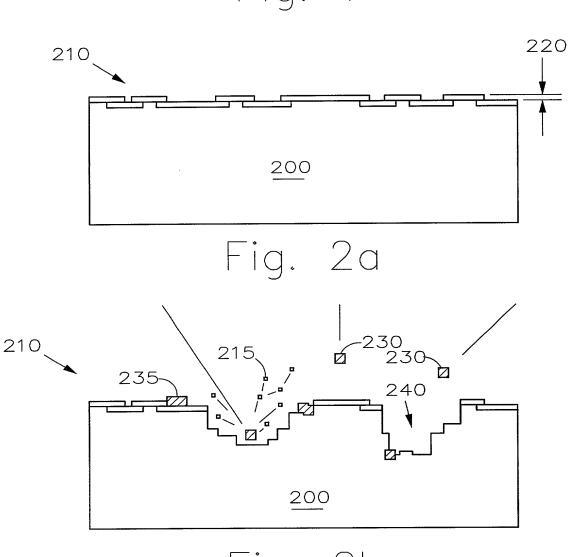


Fig. 2b

TITLE: HIGHLY RELIABLE AMORPHOUS HIGH—K GATE OXIDE ZrO2 INVENTORS NAME: Kie Y. Ahn et al. DOCKET NO.: 1303.026US1

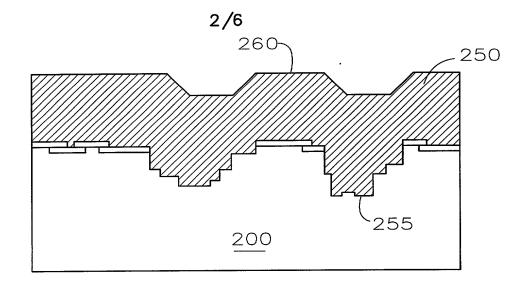


Fig. 2c

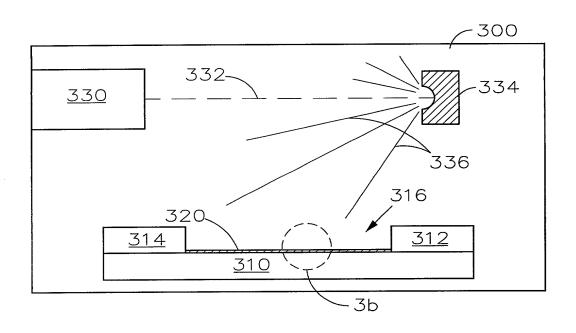


Fig. 3a

TITLE: HIGHLY RELIABLE AMORPHOUS HIGH-K GATE OXIDE ZrO2 INVENTORS NAME: Kie Y. Ahn et al. DOCKET NO.: 1303.026US1

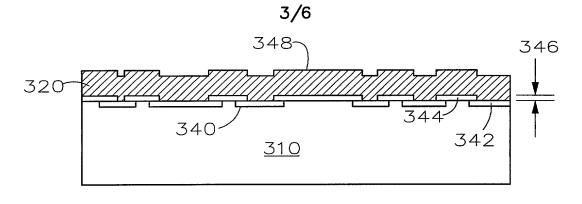


Fig. 3b

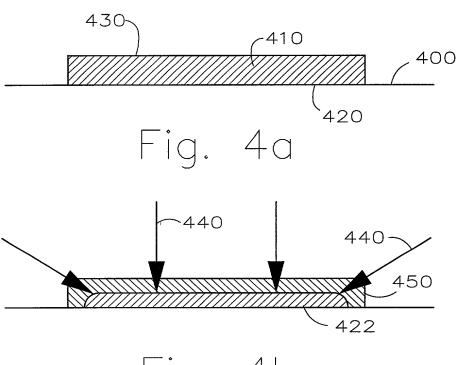
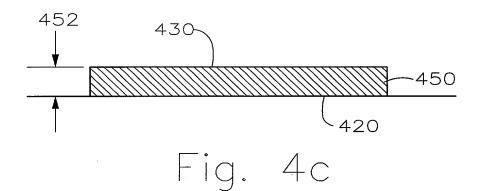


Fig. 4b



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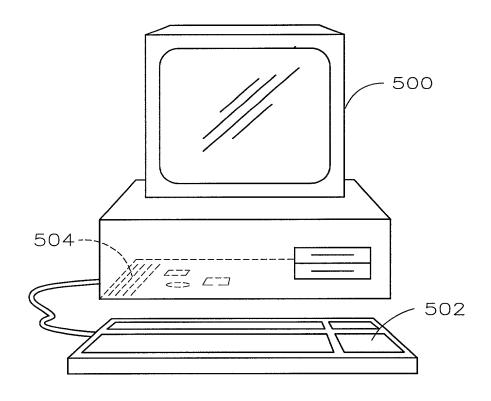


Fig. 5

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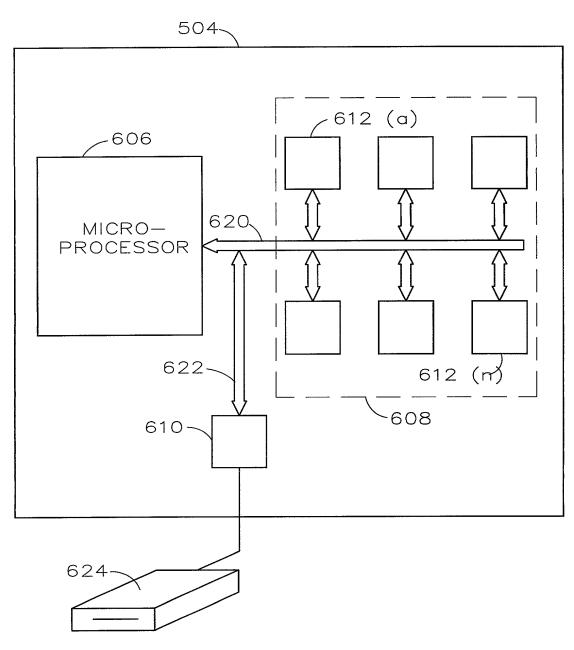


Fig. 6

TITLE: HIGHLY RELIABLE AMORPHOUS HIGH-K GATE OXIDE ZrO2 INVENTORS NAME: Kie Y. Ahn et al. DOCKET NO.: 1303.026US1

